NSN 5961-01-291-2887

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-291-2887 **Inclosure Material:** Glass **Overall Length:** 0.358 inches **Overall Height:** 0.100 inches **Overall Width:** 0.358 inches **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 9.55 regulator voltage all semiconductor device diode **Voltage Tolerance In Percent:** -5.0/+5.0 all semiconductor device diode **Current Rating Per Characteristic:** 5.50 milliamperes source cutoff current horsepower metric all semiconductor device diode **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 20 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: